# **HD74HC353**

Dual 4-to-1-line Data Selectors/Multiplexers (with 3-state outputs)

# **HITACHI**

### **Description**

Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (G) are provided for each of the two four-line sections.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common output disabled (at a high-impedance state) the low-impedance of the single enable output will drive the bus line to a high or low logic level. Each output has its own strobe (G). The output is disabled when its strobe is high.

#### **Features**

• High Speed Operation:  $t_{nd}$  (Data to Y) = 13 ns typ ( $C_L = 50 \text{ pF}$ )

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$ 

• Low Input Current: 1 µA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)



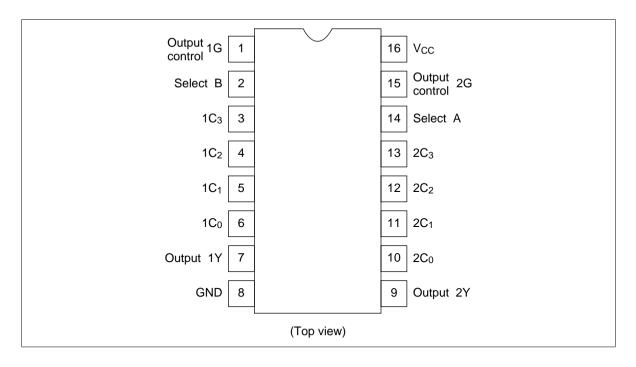
## **HD74HC353**

### **Function Table**

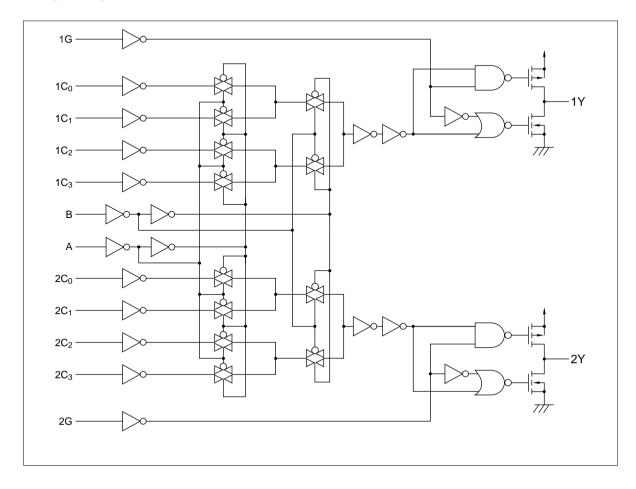
Select Input		Data In	puts		Output (	Control Output	
В	Α	C <sub>o</sub>	C <sub>1</sub>	C <sub>2</sub>	C <sub>3</sub>	G	Υ
X	Х	Х	Χ	Χ	Х	Н	Z
L	L	L	Х	Χ	Χ	L	Н
L	L	Н	Χ	Χ	Х	L	L
L	Н	Х	L	Х	Х	L	Н
L	Н	Х	Н	Х	Х	L	L
Н	L	Χ	Χ	L	Х	L	Н
Н	L	Χ	Χ	Н	Χ	L	L
Н	Н	Х	Х	Х	L	L	Н
Н	Н	Х	Х	Х	Н	L	L

Select inputs A and B are common to both sections

### **Pin Arrangement**



## Logic Diagram



# HD74HC353

### **DC** Characteristics

			Ta =	= 25°(	;	Ta = - +85°0	-40 to			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Condition	ıs
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	i —	_	3.15	_	=		
		6.0	4.2	_	_	4.2	_	=		
	V <sub>IL</sub>	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35			
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0		1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA
		4.5	4.4	4.5	_	4.4	_			
		6.0	5.9	6.0	_	5.9	_	_		
		4.5	4.18	· —		4.13	_		•	I <sub>OH</sub> = -4 mA
		6.0	5.68	i —	_	5.63	_		•	$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5	_	0.0	0.1	_	0.1			
		6.0	_	0.0	0.1	_	0.1	_		
		4.5	_	_	0.26	_	0.33	_	•	I <sub>OL</sub> = 4 mA
		6.0	_	_	0.26	_	0.33	_		I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GN	ID
Quiescent supply current	I <sub>cc</sub>	6.0	_	_	4.0	_	40	μΑ	$Vin = V_{cc} \text{ or } GN$	ID, lout = 0 μA

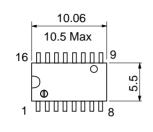
**AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

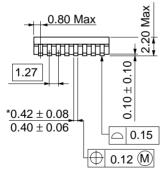
Ta = -40 to  $Ta = 25^{\circ}C$  +85°C

				(			•		
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	125	_	155	ns	Data to Y
time	$t_{\tiny PHL}$	4.5	_	13	25	_	31	_	
		6.0	_	_	21	_	26		
		2.0	_	_	160	_	200	ns	A or B to Y
		4.5	_	14	32	_	40	=	
		6.0	_	_	27	_	34	=	
Output enable	t <sub>zL</sub>	2.0	_	_	100	_	125	ns	
time	$\mathbf{t}_{_{\mathrm{ZH}}}$	4.5	_	8	20	_	25		
		6.0	_	_	17	_	21		
Output disable	t <sub>LZ</sub>	2.0	_	_	150	_	190	ns	
time	$\mathbf{t}_{HZ}$	4.5	_	11	30	_	38	_	
		6.0	_	_	26	_	33		
Output rise/fall	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
time	$t_{\text{THL}}$	4.5	_	5	15	_	19	_	
		6.0	_	_	13	_	16	=	
Input capacitance	Cin	_	_	5	10	_	10	pF	

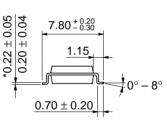
Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min  $0.25^{+0.13}_{-0.05}$  $0.48 \pm 0.10$  $2.54\pm0.25$  $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm





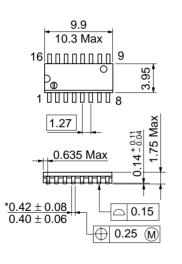


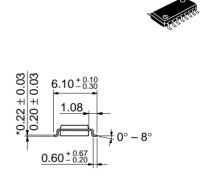


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 a

\*Dimension including the plating thickness
Base material dimension

Unit: mm





\*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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